

# SANYO Semiconductors **DATA SHEET**

LV7980 — For CRT-TV
3 in 1 RGB Driver

#### Overview

The LV7980 is a 3 in 1 RGB driver for CRT-TV.

#### **Functions**

• 3 in 1 RGB driver

• Wide bandwidth: 4.5MHz ( $V_O = 60Vp-p$ )

#### **Specifications**

**Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max		250	V
Output voltage	V <sub>OUT</sub> max		0 to V <sub>DD</sub>	V
Input Voltage	V <sub>IN</sub> max		10	V
Allowable power dissipation	Pd max	Ta ≤ 25°C, With infinite heat sink	6	W
Thermal resistance	θјс		11	°C/W
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-40 to +150	°C

#### **Operating Conditions** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	$V_{DD}$		200	V
Operating supply voltage range	V <sub>DD</sub> op		180 to 210	V

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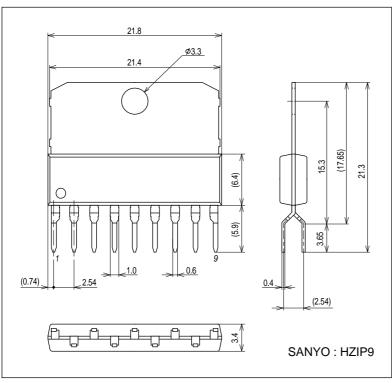
### LV7980

### **Electrical Characteristics** at Ta = 25°C, $V_{DD} = 200V$ , $VOUT = 1/2V_{DD}$ , Ccath = 10pF

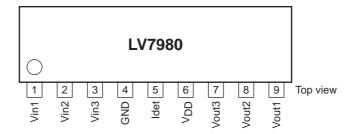
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Symbol	Conditions	Ratings			Unit
Symbol	Conditions	min	typ	max	Unit
IQ	No signal	8.0	9.4	11.0	mA
Vref			2.5		V
Ri			1.5		kΩ
Gv		76	84	92	
V <sub>O</sub>	No signal	84	94	104	V
ΔVΟ		-5	0	+5	V
Ido	VIdet = 1.8V to 5V	-50		+50	μА
Idlin	I <sub>O</sub> = -100μA to +100μA, VIdet = 1.8V to 5V	-0.9	-1.0	-1.1	
	I <sub>O</sub> = -100μA to +10mA, VIdet = 1.8V to 4V	-0.9	-1.0	-1.1	
I <sub>O</sub> max			20		mA
V <sub>O</sub> max		V <sub>DD</sub> -15			V
V <sub>O</sub> min				10	V
F1	V <sub>O</sub> = 60Vp-p		4.5		MHz
F2	V <sub>O</sub> = 100Vp-p		3.5		MHz
SR	Vi = 2.5Vp-p square wave		800		V/μs
Трсо	V <sub>O</sub> = 100Vp-p square wave		80		ns
Tst	V <sub>O</sub> = 100Vp-p square wave			350	ns
Tr	V <sub>O</sub> = 50V to 150V square wave		100		ns
Tf	V <sub>O</sub> = 150V to 50V square wave		100		ns
Ov	V <sub>O</sub> = 100Vp-p square wave		2		%
PSRR	f = 10kHz		43		dB
СТ			30		dB
	Vref Ri Gv VO ΔVO Ido Idlin IO max VO max VO min F1 F2 SR Tpco Tst Tr Tf Ov PSRR	$ I_Q \qquad \text{No signal} $ $ Vref \\ Ri \\ Gv \\ V_O \qquad \text{No signal} $ $ \Delta V_O \qquad \text{No signal} $ $ Ido \qquad VIdet = 1.8V \text{ to 5V} $ $ Idlin \qquad I_O = -100 \mu \text{A to } +100 \mu \text{A, VIdet} = 1.8V \text{ to 5V} $ $ I_O = -100 \mu \text{A to } +10 \text{mA, VIdet} = 1.8V \text{ to 4V} $ $ I_O \text{ max} \qquad V_O \text{ max} $ $ V_O \text{ min} \qquad F1 \qquad V_O = 60 \text{Vp-p} $ $ F2 \qquad V_O = 100 \text{Vp-p} \text{ square wave} $ $ Tpco \qquad V_O = 100 \text{Vp-p square wave} $ $ Tst \qquad V_O = 100 \text{Vp-p square wave} $ $ Tr \qquad V_O = 50 \text{V to } 150 \text{V square wave} $ $ Tf \qquad V_O = 150 \text{V to } 50 \text{V square wave} $ $ Ov \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 150 \text{V to } 50 \text{V square wave} $ $ Ov \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 100 \text{Vp-p square wave} $ $ Ff \qquad V_O = 100 \text{Vp-p square wave} $	No signal   8.0	Conditions           IQ         No signal         8.0         9.4           Vref         2.5           Ri         1.5         76         84           VQ         No signal         84         94           ΔVQ         No signal         84         94           ΔVQ         -5         0           Ido         VIdet = 1.8V to 5V         -50           Idlin         IQ = -100μA to +100μA, VIdet = 1.8V to 5V         -0.9         -1.0           IQ max         VQ = -100μA to +10mA, VIdet = 1.8V to 4V         -0.9         -1.0           IQ max         VQ max         VQDD-15           VQ min         VQ = 100μA to +10mA, VIdet = 1.8V to 4V         -0.9         -1.0           F1         VQ = 60Vp-p         4.5         -5           F2         VQ = 100Vp-p         3.5         -5           SR         Vi = 2.5Vp-p square wave         800	Symbol         Conditions         min         typ         max           IQ         No signal         8.0         9.4         11.0           Vref         2.5         11.5         2.5           Ri         1.5         76         84         92           VO         No signal         84         94         104           ΔVO         -5         0         +5           Ido         VIdet = 1.8V to 5V         -50         +50           Idlin         IO = -100μA to +100μA, VIdet = 1.8V to 5V         -0.9         -1.0         -1.1           IO max         20         -1.0         -1.1         -1.1           IO max         VODD-15         -0.9         -1.0         -1.1           VO max         VDD-15         -0.9         -1.0         -1.1           VO max         VDD-15         -0.9         -1.0         -1.1           VO max         VDD-15         -0.9         -1.0         -1.1           VO max         VOD-100Vp-P         4.5         -0.9         -1.0         -1.1           F2         VO = 100Vp-P square wave         800         -0.9         -0.9         -0.9         -0.9         -0.9         -0.9

# **Package Dimensions**

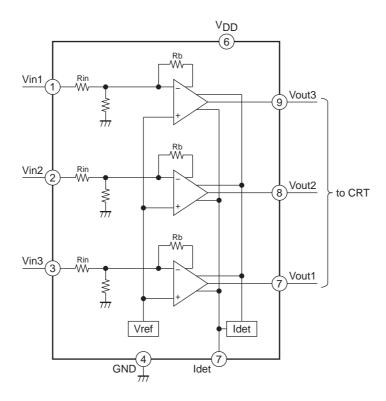
unit : mm (typ) 3374



## **Pin Assignment**



# **Block Diagram**

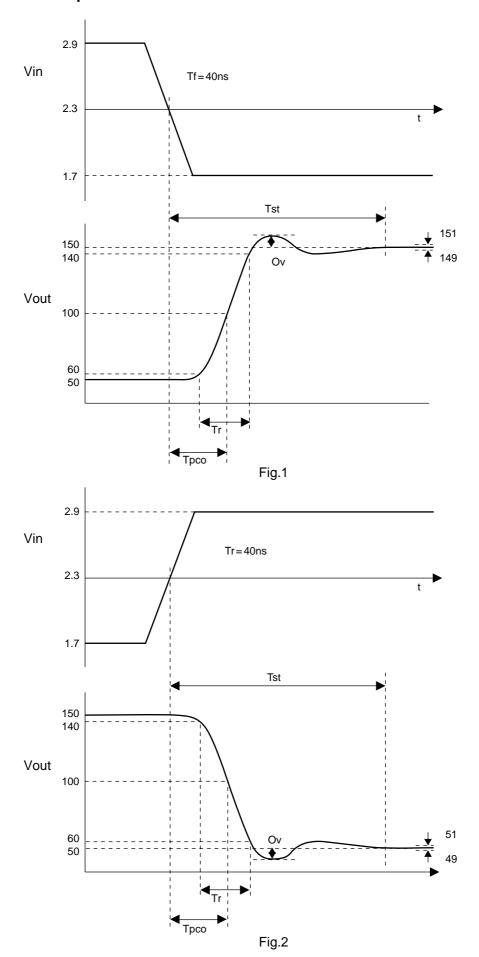


### LV7980

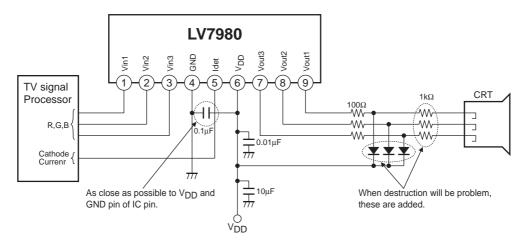
### **Pin Function**

Pin No.	Pin name	Function	Equivalent circuit
1 2 3	Vin1 Vin2 Vin3	Inverting input.	Vin 1.5kΩ WW 200Ω
4	GND	Ground.	
5	ldet	Cathode current output	Idet
6	V <sub>DD</sub>	Supply voltage	
7 8 9	Vout3 Vout2 Vout1	Output.	Vout

# Input Signal and Output Waveform



### **Application Circuit Example**



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